

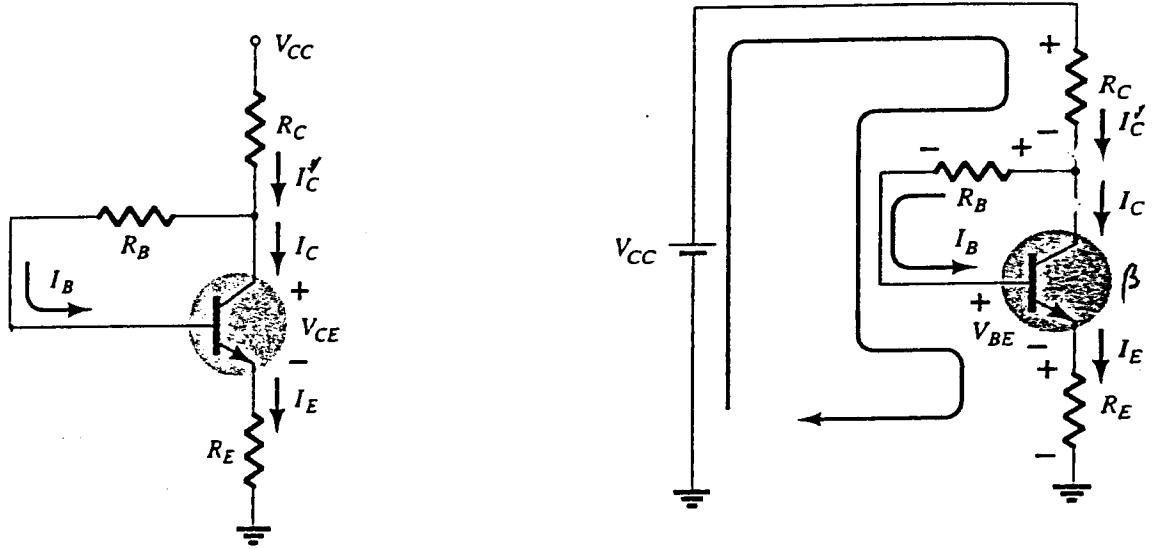
**PROBLEM 4**

**BJT Biasing with Collector and Emitter Feedback**

In class we analyzed the circuit given on the left by considering the redrawn circuit on the right.

- A. Express  $I'_C$ , and  $I_E$  in terms of  $I_B$  and  $I_C$ .
- B. Write KVL on the loops shown,; do not make the assumption that  $I_C = \beta I_B$ .
- C. NOW assume the transistor is operating in forward active region ( $I_C = \beta I_B$ ). Obtain expressions for  $I_B$ ,  $I_C$ , and  $V_{CE}$  in terms of  $R_B$ ,  $R_C$ ,  $R_E$ ,  $V_{CC}$ , and  $\beta$ .

Work details of the solution on page 9. Give Final Answers here



**FINAL ANSWERS**

$I'_C = I_C + I_B$	$I_E = I_C + I_B$
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**KVL Big Loop:**  $V_{CC} = R_C I'_C + R_B I_B + V_{BE} + R_E I_E$

**KVL Small Loop:**  $R_B I_B + V_{BE} = 0$

$I_B = \frac{V_{CC} - V_{BE}}{R_B + (\beta + 1)(R_C + R_E)}$	$I_C = \frac{V_{CC} - V_{BE}}{\frac{1}{\beta} R_B + (\frac{\beta + 1}{\beta})(R_C + R_E)}$
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$V_{CE} = V_{CC} - (R_C + R_E)(\beta + 1)I_B = V_{CC} - \frac{V_{CC} - V_{BE}}{1 + \frac{R_B}{(\beta + 1)(R_C + R_E)}}$

## PROBLEM 4 continued

To FIND  $I_B$ : replace  $I_c'$  &  $I_E$  in the Big Loop KVL by

$$I_c' = I_E = I_B + I_c = (\beta + 1) I_B$$

$$\therefore V_{CC} = R_c (\beta + 1) I_B + R_B I_B + V_{BE} + R_E (\beta + 1) I_B$$

$$\therefore \boxed{I_B = \frac{V_{CC} - V_{BE}}{R_B + (\beta + 1)(R_c + R_E)}}$$

$$I_c = \beta I_B = \frac{\beta (V_{CC} - V_{BE})}{R_B + (\beta + 1)(R_c + R_E)} = \frac{V_{CC} - V_{BE}}{\frac{1}{\beta} R_B + \left(\frac{\beta + 1}{\beta}\right) (R_c + R_E)}$$

The second form emphasizes that since  $\beta$  is large we can write  $I_c \approx \frac{V_{CC} - V_{BE}}{\frac{1}{\beta} R_B + (R_c + R_E)}$ . Now if

the resistances are chosen such that  $\frac{1}{\beta} R_B \ll (R_c + R_E)$

Then  $I_c \approx$  independent of  $\beta \Rightarrow$  Bias stability

$V_{CE}$ : going around external loop we get

$$V_{CE} = R_c I_c' + V_{CE} + R_E I_E$$

$$\text{or } \boxed{V_{CE} = V_{CC} - (R_c + R_E)(\beta + 1) I_B}$$

$$\text{or } V_{CE} = V_{CC} - \frac{(R_c + R_E)(\beta + 1)(V_{CC} - V_{CE})}{R_B + (\beta + 1)(R_c + R_E)}$$

$$V_{CE} = V_{CC} - \frac{V_{CC} - V_{BE}}{1 + \frac{R_B}{(\beta + 1)(R_c + R_E)}}$$

Now if  $R_B \ll (\beta + 1)(R_c + R_E)$  then  $V_{CE} \approx V_{CC} - (V_{CC} - V_{BE})$

&  $V_{CE} \approx V_{BE}$  again  $\Rightarrow$  Bias stability ( $V_{CE}$  also independent of  $\beta$ )

**PROBLEM 1 GRAPHICAL METHOD**

**GIVEN:** A BJT has the characteristics given in the graphs ( $I_B$ - $V_{BE}$  and  $I_C$ - $V_{CE}$ ) on PAGE 3. The BJT is connected in the following circuit.

**REQUIRED:**

A. Obtain the equations for the load lines corresponding to the input and output sides, in terms of  $R_C$ ,  $R_B$ ,  $V_{CC}$  and  $V_{in}$ .

Load Line for input side:  $R_B i_B + V_{BE} - V_{in} = 0$  OR  $i_B = -\frac{1}{R_B} V_{BE} + \frac{1}{R_B} V_{in}$

Load Line for output side:  $R_C i_C + V_{CE} - V_{CC} = 0$  OR  $i_C = -\frac{1}{R_C} V_{CE} + \frac{1}{R_C} V_{CC}$

B. The load lines drawn correspond to  $R_C = 220 \Omega$ ,  $R_B = 3.3 k\Omega$ . What is the value for  $V_{CC}$  and for  $I_{C\text{short-circuit}}$ ? Note we must refer to 2nd Graph on page 3

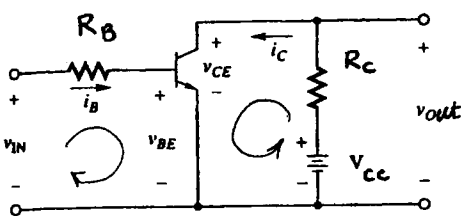
$V_{CC} = 1.0$  V,  $I_{C\text{short-circuit}} = 4.55$  mA.

C. What values of  $V_{in}$  correspond to the 7 load lines drawn on the  $I_B$ - $V_{BE}$  graph? Find values for  $V_{out}$  correspond to the 7 values for  $V_{in}$  and plot the Transfer Characteristic ( $V_{out}$  vs.  $V_{in}$ ). Also obtain values for  $I_C/I_B$ . Look at Graph on top horizontal intersection  $\Rightarrow V_{in}$

$V_{in}$ (V)	0.4	0.6	0.7	0.8	0.9	1.0	1.2
$V_{out}$ (V)	1.0	1.0	1.0	0.82	0.50	0.01	0.04
$I_C/I_B$	%	%	%	100	100	$\frac{4.1\text{mA}}{66\text{mA}} = 70$	$\frac{4.4\text{mA}}{125\text{mA}} \approx 35$

Note  $V_{out} = V_{CE}$

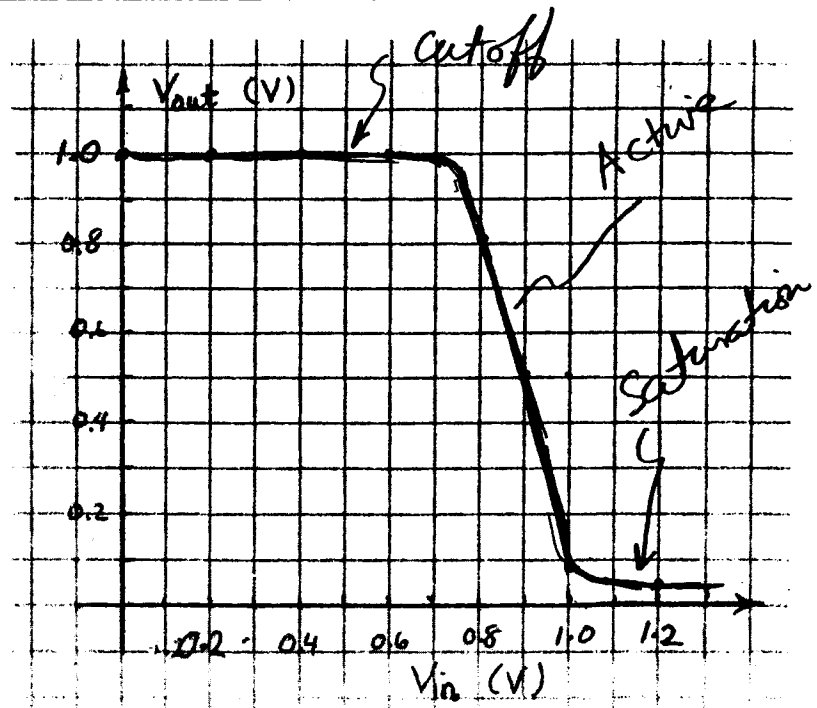
$\frac{4.1}{66} =$



$$\left\{ \begin{aligned} R_B i_B + V_{BE} - V_{in} &= 0 \Rightarrow \\ i_B &= -\frac{1}{R_B} V_{BE} + \frac{1}{R_B} V_{in} \end{aligned} \right.$$
  

$$\left\{ \begin{aligned} V_{CE} - V_{CC} + R_C i_C &= 0 \Rightarrow \\ i_C &= -\frac{1}{R_C} V_{CE} + \frac{1}{R_C} V_{CC} \end{aligned} \right.$$

$I_{C\text{sc}} = \frac{V_{CC}}{R_C} = \frac{1.0 \text{ V}}{2.2 \text{ k}\Omega} = 4.55 \text{ mA}$



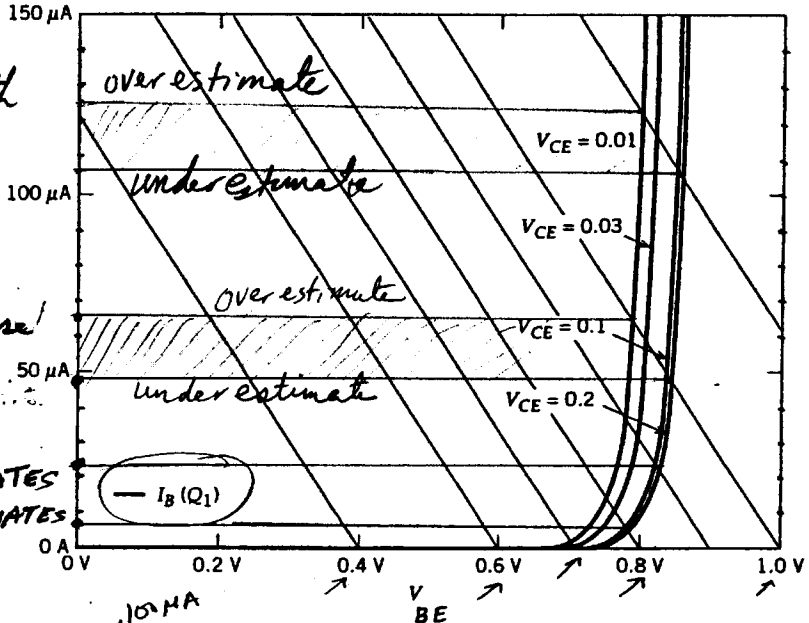
PROBLEM 1 continued

Horizontal intersects  $\Rightarrow V_{in}$

Now we use load line intersections with the diode 1V to find  $I_B$

Q: WHICH IV CURVE SHOULD WE USE

A: for  $V_{CE} > 0.1$ , we must use the rightmost for small values of  $V_{CE}$  this iv curve will UNDERESTIMATE  $I_B$ . & leftmost, OVERESTIMATES



From  $I_C - V_{CE}$  Graph it is obvious that small  $I_B \Rightarrow$  large  $V_{CE}$  & large  $I_B \Rightarrow$  small  $V_{CE}$   
(See load line cross section with constant  $I_B$  curves)

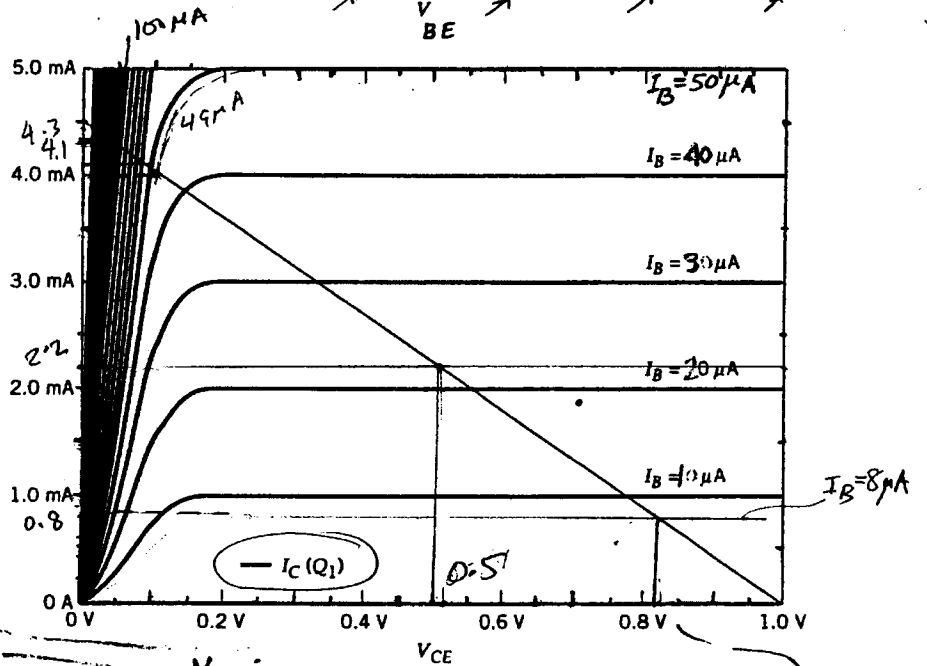
ACCURATE

Cutoff  $\left\{ \begin{array}{l} V_{in} = 0.4V \Rightarrow I_B = 0 \Rightarrow I_C = 0 \\ V_{in} = 0.6V \Rightarrow I_B = 0 \Rightarrow I_C = 0 \\ V_{in} = 0.7V \Rightarrow I_B = 0 \Rightarrow I_C = 0 \end{array} \right.$

$\left\{ \begin{array}{l} V_{in} = 0.8V \Rightarrow I_B = 8\mu A \\ V_{in} = 0.9V \Rightarrow I_B = 22\mu A \end{array} \right.$

$\left\{ \begin{array}{l} V_{in} = 1.0V \rightarrow 1.49\mu A < I_B < 66\mu A \\ V_{in} = 1.2V \rightarrow 107\mu A < I_B < 125\mu A \end{array} \right.$

Now we use the bottom graph ( $I_C$  vs.  $V_{CE}$ )



$\left\{ \begin{array}{l} 0.8V \ I_B = 8\mu A \rightarrow I_C = 0.8mA \ \& \ V_{CE} = 0.82V \\ 0.9V \ I_B = 22\mu A \rightarrow I_C = 2.2mA \ \& \ V_{CE} = 0.50V \\ 1.0V \ \left\{ \begin{array}{l} I_B = 49\mu A \ I_C = 4.0mA \ \& \ V_{CE} = 0.89V \\ I_B = 66\mu A \rightarrow I_C \approx 4.1mA \ \& \ V_{CE} \approx 0.8V \end{array} \right. \\ 1.2V \ \left\{ \begin{array}{l} I_B = 108\mu A \rightarrow I_C = 4.3mA \ \& \ V_{CE} \approx 0.85V \\ I_B = 125\mu A \rightarrow I_C \approx 4.4mA \ \& \ V_{CE} \approx 0.84V \end{array} \right. \end{array} \right.$